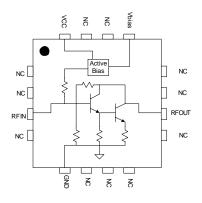


# **Product Description**

Sirenza Microdevices' SGB-4533 is a high performance SiGe HBT MMIC amplifier utilizing a Darlington configuration with an active bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 3V to 5V supply the SGB-4533 does not require a drop resistor as compared to typical Darlington amplifiers. This robust amplifier features a Class 1C ESD rating, low thermal resistance, and unconditional stability. The SGB-4533 product is designed for high linearity 3V gain block applications that require small size and minimal external components. It is on chip matched to 50 ohm and an external bias inductor choke is required for the application band.

This product is available in a RoHS Compliant and Green package with matte tin finish, designated by the "Z" package suffix.

# **Functional Block Diagram**



SGB-4533 SGB-4533Z



## DC - 3 GHz Active Bias Gain Block



## **Product Features**

- Available in Lead Free, RoHS compliant, & Green Packaging
- High reliability SiGe HBT Technology
- Robust Class 1C ESD
- Simple and small size
- P1dB = 9.5 dBm @ 1950MHz
- IP3 = 23 dBm @ 1950MHz
- Low Thermal Resistance = 76 C/W

# **Applications**

- 3V Battery operated applications
- LO buffer amp
- RF pre-driver and RF receive path

## **Key Specifications**

Symbol	Parameters: Test Conditions Z <sub>0</sub> = 50Ω, V <sub>CC</sub> = 3.0V, Ic = 56mA, T = 30°C)	Unit	Min.	Тур.	Max.
f <sub>O</sub>	Frequency of Operation	MHz	DC		3000
	Small Signal Gain – 850MHz			25.0	
S <sub>21</sub>	Small Signal Gain – 1950MHz	dB	17.0	18.5	20.0
	Small Signal Gain – 2400MHz			17.0	
	Output Power at 1dB Compression – 850MHz			10.5	
P <sub>1dB</sub>	Output Power at 1dB Compression – 1950MHz	dBm	8.0	9.5	
	Output Power at 1dB Compression – 2400MHz			9.5	
OIP3	Output IP3 – 850MHz			24.5	
	Output IP3 – 1950MHz	dB	20.5	23.0	
	Output IP3 – 2400MHz			23.0	
IRL	Input Return Loss @ 1950MHz	dB	9.0	12.0	
ORL	Output Return Loss @ 1950MHz	dB	12.0	16.0	
lc	Current	mA	48	56	62
NF	Noise Figure @1950MHz	dB		3.5	4.5
R <sub>th, j-l</sub>	Thermal Resistance (junction - lead)	°C/W		76	

The information provided herein is believed to be reliable at press time. Sirenza Microdevices assumes no responsibility for inaccuracies or ommisions.

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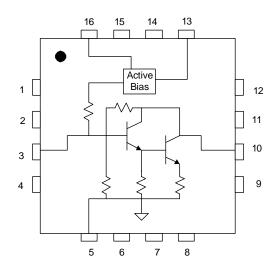
## Detailed Performance Table: Vcc=3V, Ic=56mA, T=25C, Z=50ohms

Symbol	Parameter	Units	100MHz	500MHz	850MHz	1950MHz	2400MHz	3500MHz
G	Small Signal Gain		27.3	26.3	25.0	18.5	17.0	12.9
OIP3	Output 3rd Order Intercept Point			24.5	24.5	23.0	23.0	
P1dB	B Output Power at 1dB Compression			11.0	10.5	9.5	9.5	
IRL	Input Return Loss	dB	19.0	16.9	15.6	12.0	11.0	7.7
ORL	Output Return Loss	dB	16.5	21.4	24.1	16.0	16.1	17.2
S12	Reverse Isolation	dB	30.9	29.9	29.5	27.6	26.4	24.2
NF	Noise Figure	dB	4.6	3.0	3.0	3.5	4.1	4.9

# **Pin Out Description**

• • • •	Description	
Pin#	Function	Description
1,2,4,6, 7,8,11, 12,14	NC	These are no connect pins. Leave them unconnected on the PC board.
3	RFIN	RF input pin. A DC voltage should not be connected externally to this pin
5	GND	An extra ground pin that is connected to the backside exposed paddle. Connection is optional.
10	RFOUT	RF Output pin. Bias is applied to the Darlington stage thru this pin.
13	VBIAS	This pin sources the current from the active bias circuit. Connect to pin 10 thru an inductor choke.
16	VCC	This is Vcc for the active bias circuit.
Back- side	GND	The backside exposed paddle is the main electrical GND and requires multiple vias in the PC board to GND. It is also the main thermal path.

## **Simplified Device Schematic**





#### **Caution: ESD Sensitive**

Appropriate precaution in handling, packaging and testing devices must be observed.

## **Absolute Maximum Ratings**

Parameters	Value	Unit
Current (Ic total)	120	mA
Device Voltage (V <sub>D</sub> )	5	V
Power Dissipation	0.4	W
Operating Lead Temperature (T <sub>L</sub> )	-40 to +85	°C
RF Input Power	20	dBm
Storage Temperature Range	-40 to +150	°C
Operating Junction Temperature (T <sub>J</sub> )	+150	°C

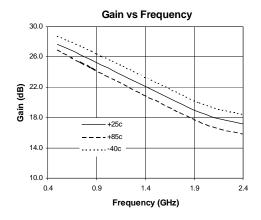
Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation the device voltage and current must not exceed the maximum operating values specified in the table on page one.

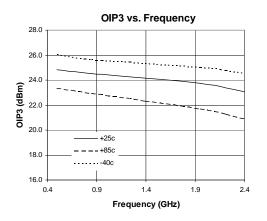
Bias conditions should also satisfy the following expression:  $I_DV_D < \left(T_J - T_L\right)/\,R_{TH^{'}}\,j\text{-}I$ 

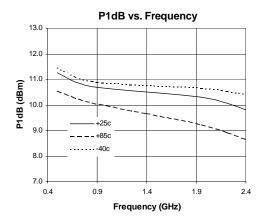


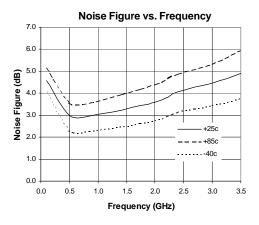


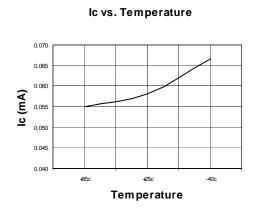
# Evaluation Board Data ( $Vcc=V_{BIAS} = 3.0V$ , $I_c = 56mA$ ) Bias Tee substituted for DC feed inductor (L1)

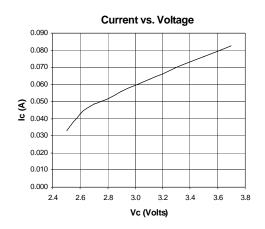








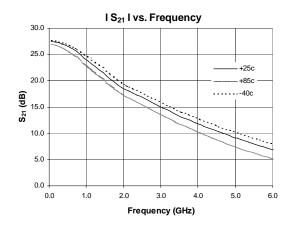


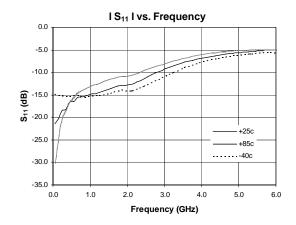


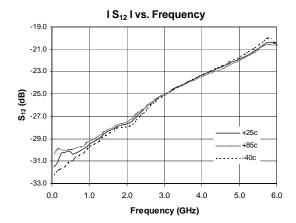


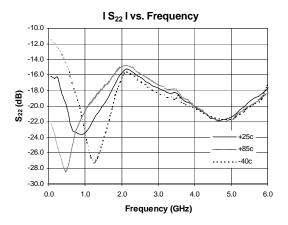
# SGB-4533 DC-3GHz Active Bias Gain Block

# Evaluation Board Data ( $Vcc=V_{BIAS} = 3.0V$ , $I_c = 56mA$ ) Bias Tee substituted for DC feed inductor (L1)



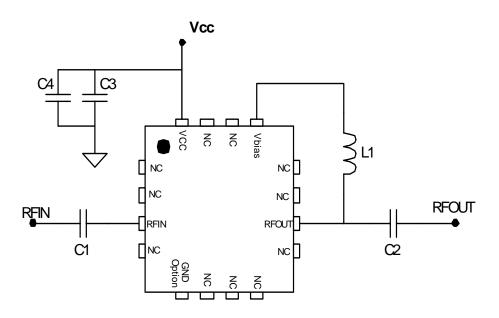




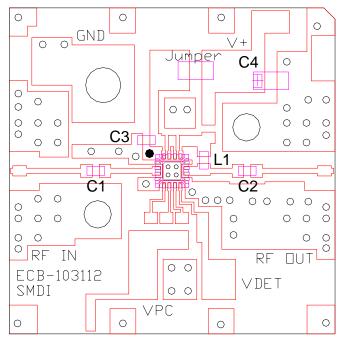




#### Typical Evaluation Board Schematic for 3.0V



# Evaluation Board - Board material GETEK, 31mil thick, Dk=4.2, 1 oz. copper



#### **Component Values By Band**

Designator	500MHz	850MHz	1950MHz	2400MHz
C3	1000pF	1000pF	1000pF	1000pF
C4*	1uF	1uF	1uF	1uF
C1, C2	220pF	68pF	43pF	22pF
L1	68 nH	33nH	22nH	18nH

<sup>\*</sup> C4 is optional depending on application and filtering. Not required for SGB device operation.

**Note:** The amplifier can be run from a 5V supply by simply inserting a 33 ohm resistor in series with Vcc.



# SGB-4533 DC-3GHz Active Bias Gain Block

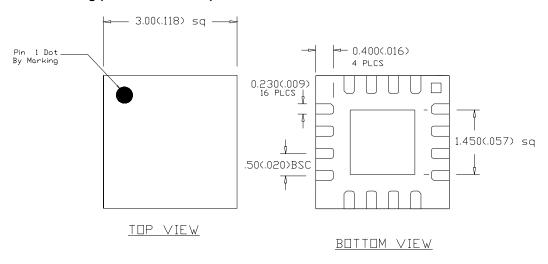
#### **Part Marking**

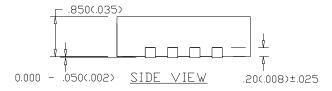
The part will be symbolized with an "SGB-4533" for Sn/Pb plating or "SGB-45Z" for RoHS green compliant product. Marking designator will be on the top surface of the package.

#### **Part Number Ordering Information**

Part Number	Reel Size	Devices/Reel		
SGB-4533	13"	3000		
SGB-4533Z	13"	3000		

#### Package Outline Drawing (Dimensions in mm)





## Recommended Land Pattern (dimensions in mm[in].):

# Recommended PCB Soldermask (SMOBC) for Land Pattern(dimensions in mm[in]):

